TF21814



High-Side and Low-Side Gate Driver

Features

- Floating high-side driver in bootstrap operation to 600V
- Drives two N-channel MOSFETs or IGBTs in a half bridge configuration
- 1.9A source / 2.3A sink output current capability
- Outputs tolerant to negative transients
- Wide low side gate driver supply voltage: 10V to 20V
- Logic input (HIN and LIN) 3.3V capability
- Schmitt triggered logic inputs with internal pull down
- Undervoltage lockout for high and low side drivers
- Extended temperature range: -40°C to +125°C

Description

The TF21814 is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. Telefunken's high voltage process enables the TF21814's high side to switch to 600V in a bootstrap operation.

The TF21814 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

The TF21814 is offered in PDIP-14 and SOIC-14(N) packages and operate over an extended -40 $^\circ$ C to +125 $^\circ$ C temperature range.

Applications

- Motor Drivers
- Motor Controls
- DC-DC Converters
- Class D Power Amplifiers

4(N)



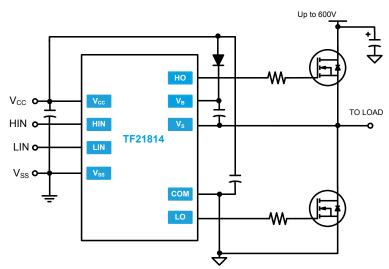
SOIC-14(N)

Ordering Information

Year Year Week Week

PART NUMBER	PACKAGE	PACK / Qty	MARK
TF21814-3BS	PDIP-14	Tube / 25	YYWW TF21814 Lot ID
TF21814-TUU	SOIC-14(N)	Tube / 50	YYWW TF21814
TF21814-TUH	SOIC-14(N)	T&R / 2500	Lot ID

Typical Application



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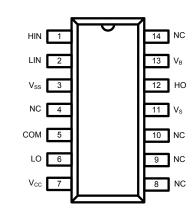




Pin Diagrams

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High-Side and Low-Side Gate Driver

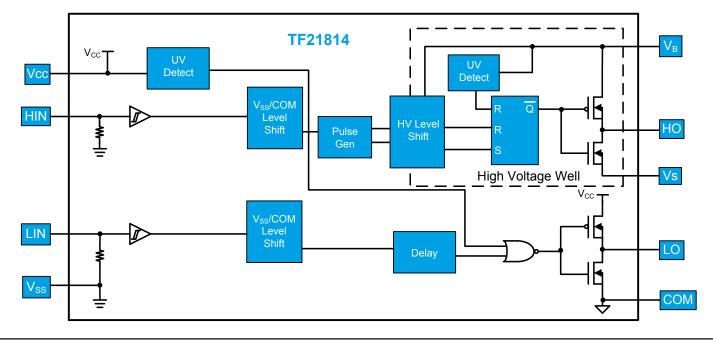


Top View: PDIP-14, SOIC-14

Pin Descriptions

PIN NAME	PIN NUMBER	PIN DESCRIPTION
HIN	1	Logic input for high-side gate driver output, in phase with HO.
LIN	2	Logic input for low-side gate driver output, in phase with LO.
СОМ	3	Low-side and logic return
LO	4	Low-side gate drive output
V _{cc}	5	Low-side and logic fixed supply
V _s	6	High-side floating supply return
НО	7	High-side gate drive output
V _B	8	High-side floating supply

Functional Block Diagram





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Absolute Maximum Ratings (NOTE1)

$V_{\rm B}$ - High side floating supply voltage0.3V to +624V
V_s - High side floating supply offset voltage V_B -24V to V_B +0.3V
V_{HO} -Highside floating output voltageV _s -0.3VtoV _B +0.3V
dV _s /dt - Offset supply voltage transient50 V/ns
V_{cc} - Low-side fixed supply voltage0.3V to +24V
V_{ss}^{-} - Logic supply offset voltageV _{cc} -24V to V _{cc} +0.3V
V_{10} - Low-side output voltage0.3V to V_{cc} +0.3V
V_{IN} - Logic input voltage (HIN and LIN)0.3V to V_{CC} +0.3V

NOTE1 Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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P_D - Package power dissipation at $T_A \le 25 \text{ °C}$ SOIC-14 PDIP-14	
SOIC-14(N) Thermal Resistance (N0TE2) θ _{JA} PDIP-14 Thermal Resistance (N0TE2)	120°C/W
θ _{JA}	75°C/W
T_J - Junction operating temperature T_L - Lead Temperature (soldering, 10 seconds) T_{stg} - Storage temerature	+300 °C

NOTE2 Thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Recommended Operating Conditions

Symbol	Parameter	MIN	МАХ	Unit
V _B	High side floating supply absolute voltage	V _s + 10	V _s + 20	V
V _s	High side floating supply offset voltage	NOTE3	600	V
V _{HO}	High side floating output voltage	V _s	V _B	V
V _{cc}	Low side fixed supply voltage	10	20	V
V _{LO}	Low side output voltage	0	V _{cc}	V
V _{IN}	Logic input voltage (HIN and LIN)	0	V _{cc}	V
V _{ss}	Logic Ground	-5	+5	V
T _A	Ambient temperature	-40	125	°C

NOTE3 Logic operational for VS of -5V to +600V. Logic state held for VS of -5V to -VBS



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DC Electrical Characteristics (NOTE4)

 $V_{\text{BIAS}}(V_{\text{CC}},V_{\text{BS}}) = 15V, T_{\text{A}} = 25\ ^{\circ}\text{C}$, unless otherwise specified.

Symbol	Parameter	Conditions	MIN	ТҮР	МАХ	Unit	
V _{IH}	Logic "1" input voltage		2.5				
V _{IL}	Logic "0" input voltage	$V_{cc} = 10V$ to 20V			0.8		
V _{OH}	High level output voltage, V _{BIAS} - V _O	$I_0 = 0A$			1.4	v	
V _{ol}	Low level output voltage, V _o	$I_0 = 20 \text{mA}$			0.2	v	
I _{LK}	Offset supply leakage current	VB = VS = 600V			50		
I _{BSQ}	Quiescent V _{BS} supply current	V _{IN} =0V or 5V	20	60	150	μΑ	
I _{ccq}	Quiescent V _{cc} supply current	V _{IN} =0V or 5V	50	120	240	μA	
I _{IN+}	Logic "1" input bias current	V _{IN} = 5V		25	60		
I _{IN-}	Logic "0" input bias current	V _{IN} =0V			5.0	μΑ	
V_{BSUV+}	V _{BS} supply under-voltage positive going threshold		8.0	8.9	9.8		
V _{BSUV-}	V _{BS} supply under-voltage negative going threshold		7.4	8.2	9.0	V	
V _{CCUV+}	V _{cc} supply under-voltage positive going threshold		8.0	8.9	9.8		
V _{ccuv-}	V _{cc} supply under-voltage negative going threshold		7.4	8.2	9.0		
I ₀₊	Output high short circuit pulsed current	$V_0 = 0V, PW \le 10 \ \mu s$	1.4	1.9			
I ₀₋	Output low short circuit pulsed current	$V_{o} = 15V$, PW $\leq 10 \ \mu s$	1.8	2.3		A	

NOTE4 The V_{IV} V_{TV} and I_{N} parameters are applicable to the two logic input pins: LIN and HIN. The V_{0} and I_{0} parameters are applicable to the respective output pins: HO and LO.



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AC Electrical Characteristics

 $V_{BIAS}(V_{CC}, V_{BS}) = 15V, C_L = 1000 \text{pF}$, and $T_A = 25 \text{ °C}$, unless otherwise specified.

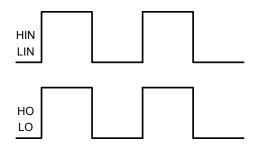
Symbol	Parameter	Conditions	MIN	ТҮР	MAX	Unit
t _{on}	Turn-on propogation delay	$V_s = 0V$		180	270	
t _{off}	Turn-off propogation delay	$V_s = 0V \text{ or } 600V$		220	330	
t _{DM}	Delay matching, HS & LS turn-on/off				35	
t _r	Turn-on rise time			40	60	ns
t _r	Turn-off fall time	$V_s = 0V$		20	35	

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Timing Waveforms



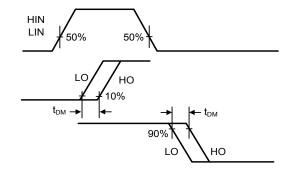


Figure 1. Input / Output Timing Diagram

Figure 2. Delay Matching Waveform Definitions

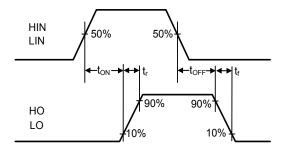


Figure 3. Switching Time Waveform Definitions

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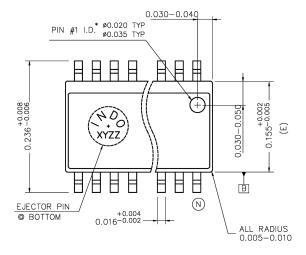


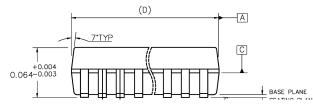
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Package Dimensions (SOIC-14 N)

Please contact support@tfsemi.com for package availability.

Т	REV	DESCRIPTION	DATE	BY	REV	DESCRIPTION	DATE	
	M	UPDATE FOOT LENGTH MEASUREMENT METHOD	04SEPT06	AGUS S/PE	J	CHANGE FR .035/.045 & FR .045/.055 CHANGE PIN 1 DIA FR \$.045 & ADD \$.020 TYP	07FEB01	~
	N	CHANGE COMPANY NAME & LOGO REMOVE "GULL WING " FROM TITLE UPDATE 16L VARIATION	13JUN08	AGUS S/PE	к	UPDATE TABLE, REMOVE CONVENTIONAL MOLD COLUMN	29APR03	H/
					L	UPDATE TABLE, REMOVE MGP MOLD FOR OWN SOIC STANDARD LEAD FRAME	01JUL04	s

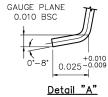




ALL DIMENSIONS ARE IN INCHES UNLESS OTHERWISE NOTED

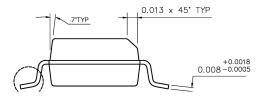
NOTES:

- 1. "D" & "E" ARE REFERENCE DATUMS AND DO NOT INCLUDE MOLD FLASH OR PROTRUSION. MOLD FLASH OR PROTRUSION SHALL NOT EXCEED 6 MILS PER SIDE.
- 2. "N" IS THE NUMBER OF TERMINAL POSITIONS.
- 3. FORMED LEADS SHALL BE PLANAR WITH RESPECT TO ONE ANOTHER WITHIN 3 MILS (SEATING PLANE) OUTGOING ASSEMBLY & 4 MILS AFTER TEST.
- 4. THE BOTTOM PACKAGE LEAD SIDE MAY BE BIGGER THAN THE TOP PACKAGE LEAD SIDE BY 4 MILS (2 MILS PER SIDE). BOTTOM PACKAGE DIMENSION SHALL FOLLOW DIMENSION STATED IN THIS DRAWING.
- 5 THE BOTTOM EJECTOR PIN CONTAINS COUNTRY OF ORIGIN "INDO" AND MOLD ID. (REFER TO TABLE FOR OPTION).
- 6. THIS DRAWING CONFORMS TO JEDEC REF. MS-012 REV. E



						MGP	MOLD	
		יט	/ARIATI	UN	STAN	IDARD	MAT	rix
	N	MIN	NOM	мах	PIN 1 I.D.	eject Pin	PIN 1 I.D.	eject Pin
	08	0.189	0.193	0.196	N/A		YES	YES
	14	0.337	0.339	0.344	YES	NO	YES	YES
⋒	16	0.386	0.390	0.393	N	/A	YES	YES





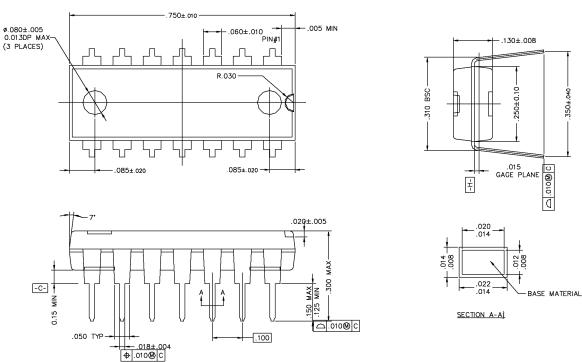


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350±.040

Package Dimensions (PDIP-14)

Please contact support@tfsemi.com for package availability.



ALL DIMENSIONS ARE IN INCHES UNLESS OTHERWISE NOTED

Note: Drawing conforms to jedec ref. MS-001 rev D

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Notes

High-Side and Low-Side Gate Driver

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